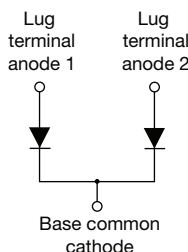


# HEXFRED® Ultrafast Soft Recovery Diode, 240 A


**TO-244**


## FEATURES

- Very low  $Q_{rr}$  and  $t_{rr}$
- UL approved file E222165 
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT

## BENEFITS

- Reduced RFI and EMI
- Reduced snubbing

## DESCRIPTION / APPLICATIONS

HEXFRED® diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and  $di_F/dt$  simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

## PRIMARY CHARACTERISTICS

|                       |                           |
|-----------------------|---------------------------|
| $I_{F(AV)}$           | 240 A                     |
| $V_R$                 | 400 V                     |
| $I_{F(DC)}$ at $T_C$  | 197 A at 100 °C           |
| Package               | TO-244                    |
| Circuit configuration | Two diodes common cathode |

## ABSOLUTE MAXIMUM RATINGS

| PARAMETER                                        | SYMBOL         | TEST CONDITIONS                                                    | MAX.        | UNITS |
|--------------------------------------------------|----------------|--------------------------------------------------------------------|-------------|-------|
| Cathode to anode voltage                         | $V_R$          |                                                                    | 400         | V     |
| Continuous forward current                       | $I_F$          | $T_C = 25\text{ °C}$                                               | 395         | A     |
|                                                  |                | $T_C = 100\text{ °C}$                                              | 197         |       |
| Single pulse forward current                     | $I_{FSM}$      | Limited by junction temperature                                    | 900         |       |
| Non-repetitive avalanche energy                  | $E_{AS}$       | $L = 100\text{ }\mu\text{H}$ , duty cycle limited by maximum $T_J$ | 1.4         | mJ    |
| Maximum power dissipation                        | $P_D$          | $T_C = 25\text{ °C}$                                               | 658         | W     |
|                                                  |                | $T_C = 100\text{ °C}$                                              | 263         |       |
| Operating junction and storage temperature range | $T_J, T_{Stg}$ |                                                                    | -55 to +150 | °C    |

## ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)

| PARAMETER                             | SYMBOL          | TEST CONDITIONS                                 |            | MIN. | TYP. | MAX. | UNITS |
|---------------------------------------|-----------------|-------------------------------------------------|------------|------|------|------|-------|
| Cathode to anode<br>breakdown voltage | V <sub>BR</sub> | I <sub>R</sub> = 100 μA                         |            | 400  | -    | -    | V     |
| Maximum forward voltage               | V <sub>FM</sub> | I <sub>F</sub> = 120 A                          | See fig. 1 | -    | 1.1  | 1.47 |       |
|                                       |                 | I <sub>F</sub> = 240 A                          |            | -    | 1.3  | 1.5  |       |
|                                       |                 | I <sub>F</sub> = 120 A, T <sub>J</sub> = 125 °C |            | -    | 1.0  | 1.2  |       |
| Maximum reverse<br>leakage current    | I <sub>RM</sub> | T <sub>J</sub> = 125 °C, V <sub>R</sub> = 400 V | See fig. 2 | -    | 660  | 5000 | μA    |
| Junction capacitance                  | C <sub>T</sub>  | V <sub>R</sub> = 200 V                          | See fig. 3 | -    | 280  | 380  | pF    |
| Series inductance                     | L <sub>S</sub>  | From top of terminal hole to mounting plane     |            | -    | 6.0  | -    | nH    |

**DYNAMIC RECOVERY CHARACTERISTICS** ( $T_J = 25\text{ }^{\circ}\text{C}$  unless otherwise specified)

| PARAMETER                                   | SYMBOL           | TEST CONDITIONS                                                                   | MIN. | TYP. | MAX. | UNITS            |
|---------------------------------------------|------------------|-----------------------------------------------------------------------------------|------|------|------|------------------|
| Reverse recovery time<br>See fig. 5         | $t_{rr}$         | $I_F = 1.0\text{ A}$ , $dI_F/dt = 200\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$ | -    | 50   | -    | ns               |
|                                             |                  | $T_J = 25\text{ }^{\circ}\text{C}$                                                | -    | 77   | 120  |                  |
|                                             |                  | $T_J = 125\text{ }^{\circ}\text{C}$                                               | -    | 290  | 440  |                  |
| Peak recovery current<br>See fig. 6         | $I_{RRM}$        | $T_J = 25\text{ }^{\circ}\text{C}$                                                | -    | 7.5  | 14   | A                |
|                                             |                  | $T_J = 125\text{ }^{\circ}\text{C}$                                               | -    | 16   | 30   |                  |
| Reverse recovery charge<br>See fig. 7       | $Q_{rr}$         | $T_J = 25\text{ }^{\circ}\text{C}$                                                | -    | 290  | 780  | nC               |
|                                             |                  | $T_J = 125\text{ }^{\circ}\text{C}$                                               | -    | 2300 | 6300 |                  |
| Peak rate of recovery current<br>See fig. 8 | $dI_{(rec)M}/dt$ | $T_J = 25\text{ }^{\circ}\text{C}$                                                | -    | 320  | -    | A/ $\mu\text{s}$ |
|                                             |                  | $T_J = 125\text{ }^{\circ}\text{C}$                                               | -    | 270  | -    |                  |

**THERMAL - MECHANICAL SPECIFICATIONS**

| PARAMETER                                      | SYMBOL         | MIN.     | TYP. | MAX.     | UNITS                       |
|------------------------------------------------|----------------|----------|------|----------|-----------------------------|
| Maximum junction and storage temperature range | $T_J, T_{Stg}$ | - 55     | -    | 150      | $^{\circ}\text{C}$          |
| Thermal resistance, junction to case           | $R_{thJC}$     | -        | -    | 0.19     | $^{\circ}\text{C}/\text{W}$ |
|                                                |                | -        | -    | 0.095    |                             |
| Typical thermal resistance, case to heatsink   | $R_{thCS}$     | -        | 0.10 | -        | $^{\circ}\text{C}/\text{W}$ |
| Weight                                         |                | -        | 68   | -        | g                           |
|                                                |                | -        | 2.4  | -        | oz.                         |
| Mounting torque <sup>(1)</sup>                 | center hole    | 30 (3.4) | -    | 40 (4.6) | lbf · in<br>(N · m)         |
|                                                |                | 12 (1.4) | -    | 18 (2.1) |                             |
| Terminal torque                                |                | 30 (3.4) | -    | 40 (4.6) |                             |
| Vertical pull                                  |                | -        | -    | 80       |                             |
| 2" lever pull                                  |                | -        | -    | 35       | lbf · in                    |

**Note**

- <sup>(1)</sup> Mounting surface must be smooth, flat, free of burrs or other protrusions. Apply a thin even film of thermal grease to mounting surface. Gradually tighten each mounting bolt in 5 to 10 lbf · in steps until desired or maximum torque limits are reached

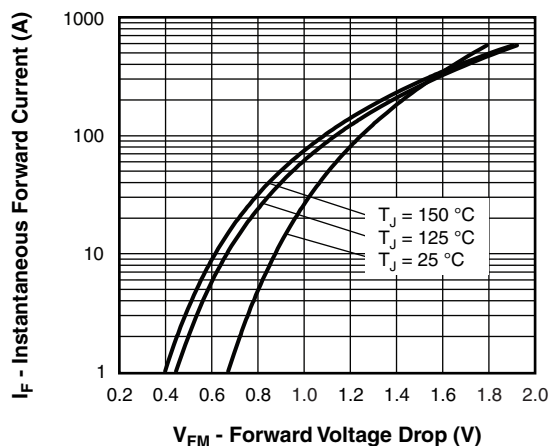


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

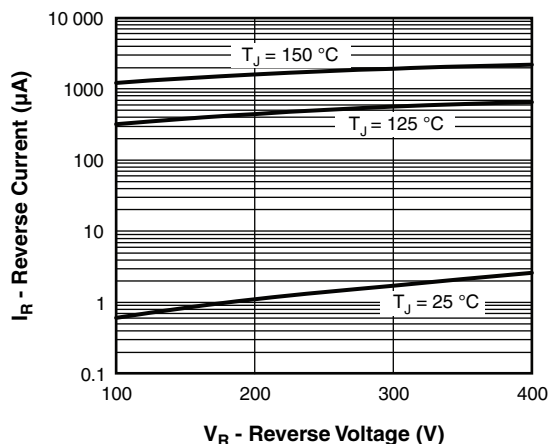


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

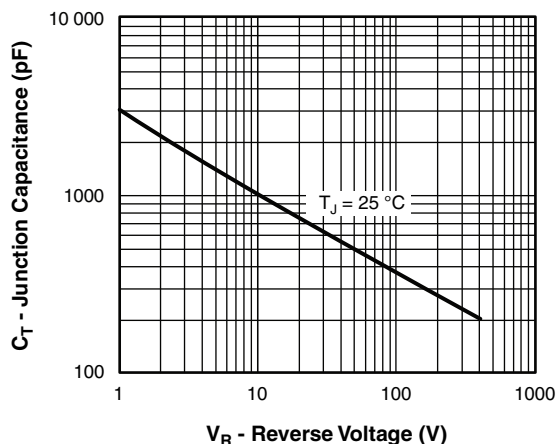


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

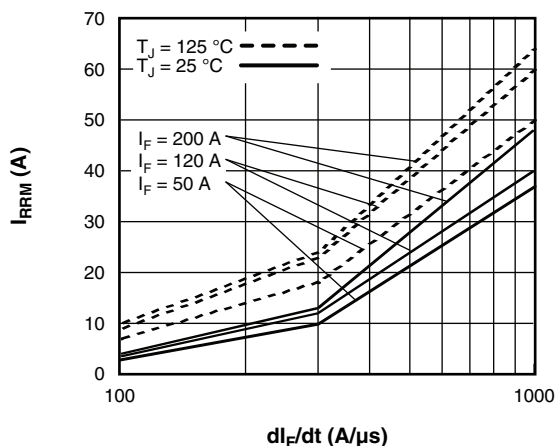


Fig. 6 - Typical Recovery Current vs.  $dI_F/dt$  (Per Leg)

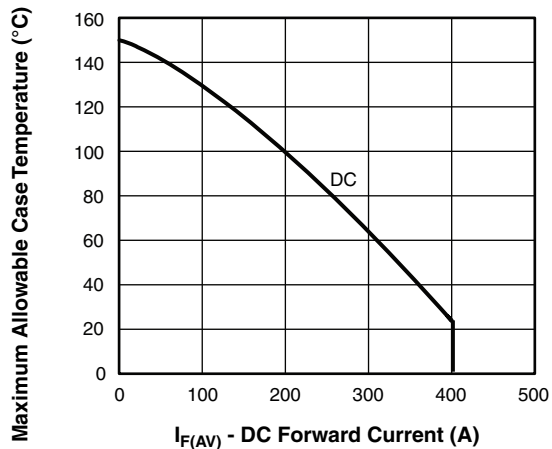


Fig. 4 - Maximum Allowable Case Temperature vs. DC Forward Current (Per Leg)

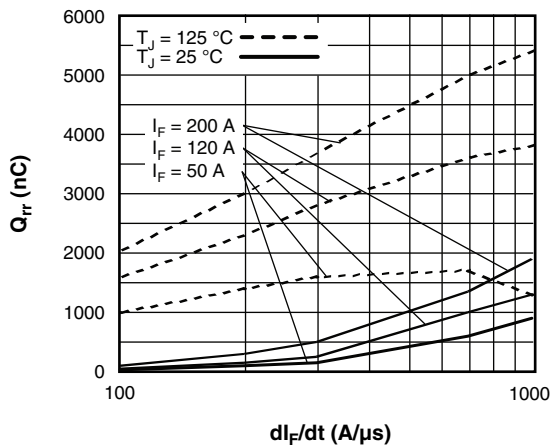


Fig. 7 - Typical Stored Charge vs.  $dI_F/dt$  (Per Leg)

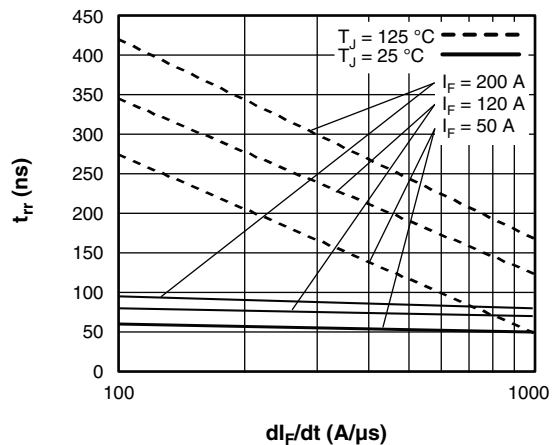


Fig. 5 - Typical Reverse Recovery Time vs.  $dI_F/dt$  (Per Leg)

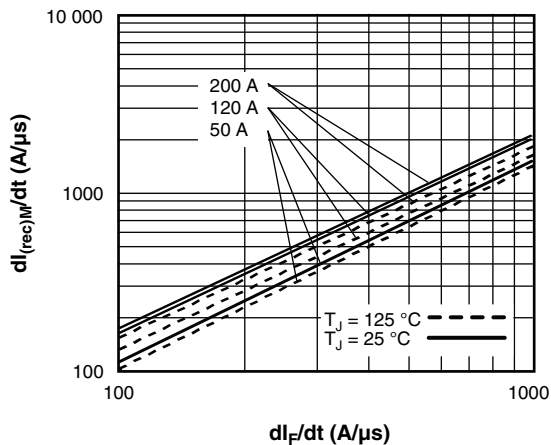


Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $dI_F/dt$  (Per Leg)

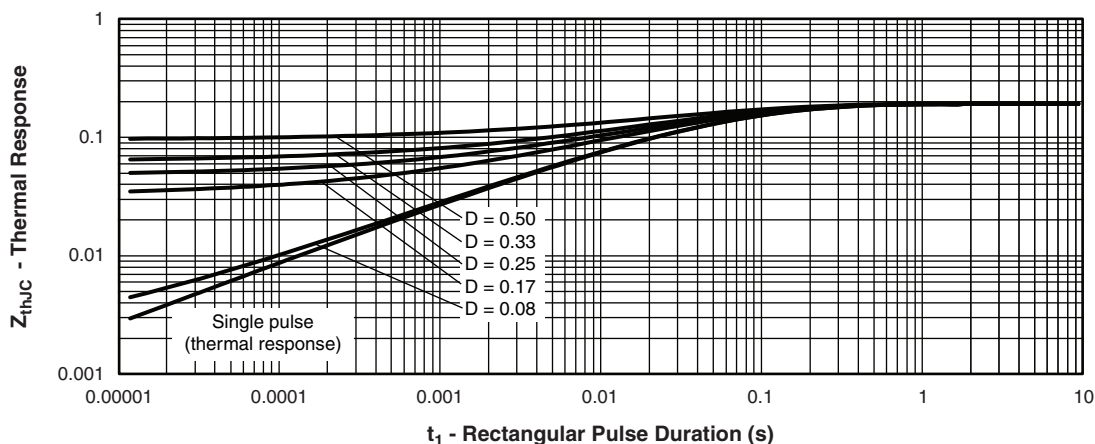


Fig. 9 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

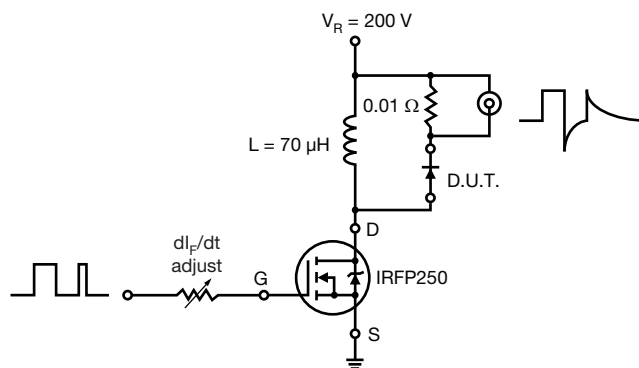


Fig. 10 - Reverse Recovery Parameter Test Circuit

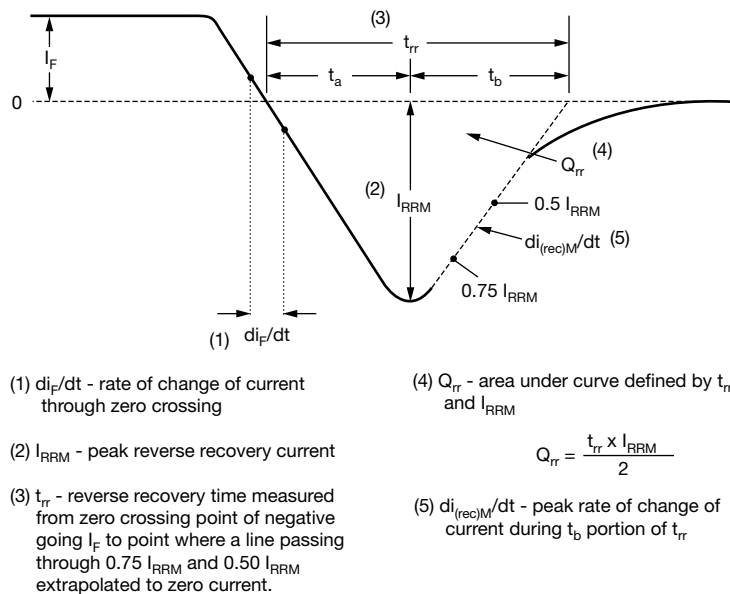


Fig. 11 - Reverse Recovery Waveform and Definitions

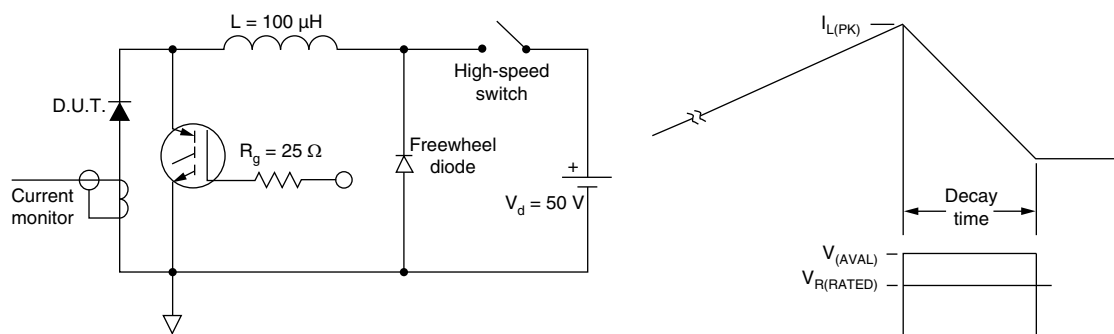


Fig. 12 - Avalanche Test Circuit and Waveforms

## ORDERING INFORMATION TABLE

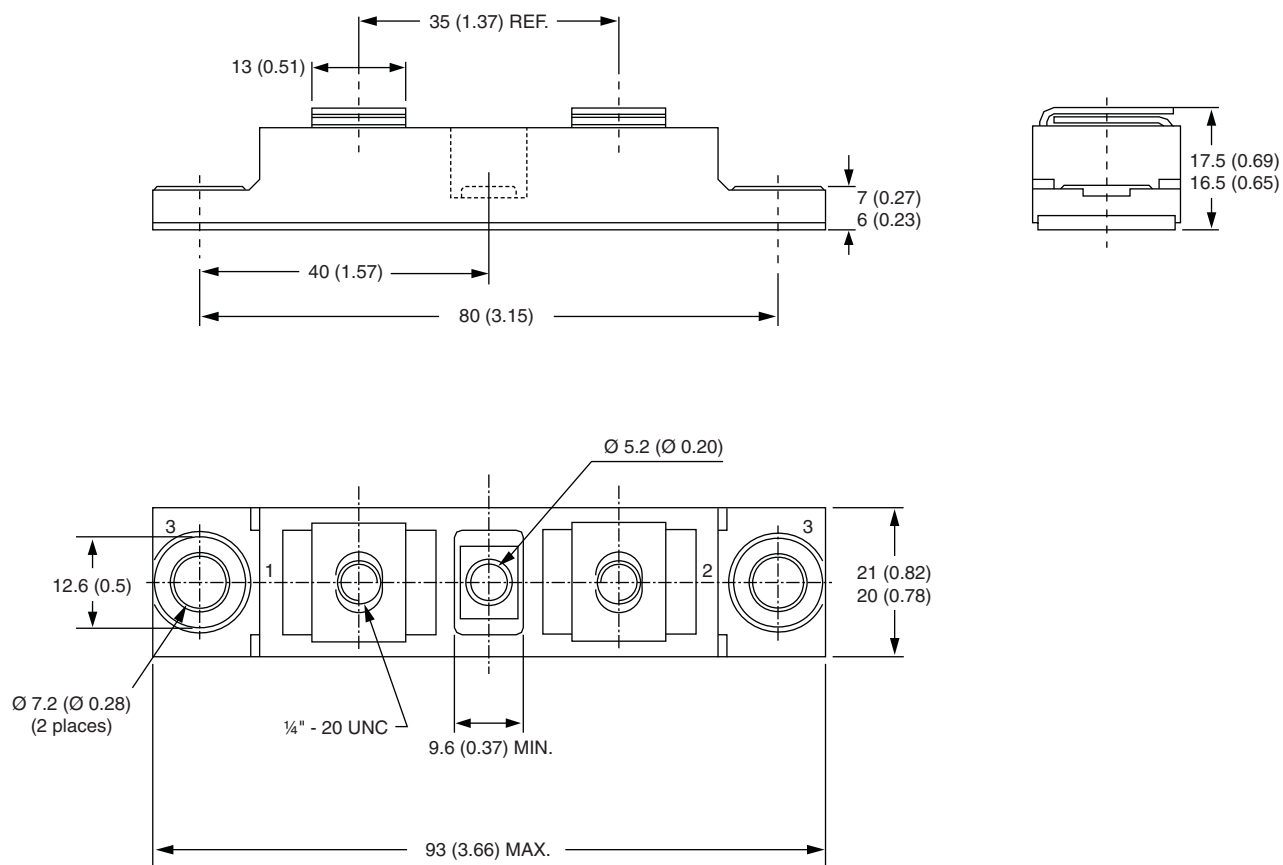
| Device code | VS-                                  | HFA | 240 | NJ | 40 | C | PbF |
|-------------|--------------------------------------|-----|-----|----|----|---|-----|
|             | 1                                    | 2   | 3   | 4  | 5  | 6 | 7   |
| 1           | Vishay Semiconductors product        |     |     |    |    |   |     |
| 2           | HEXFRED® family, electron irradiated |     |     |    |    |   |     |
| 3           | Average current rating               |     |     |    |    |   |     |
| 4           | NJ = TO-244                          |     |     |    |    |   |     |
| 5           | Voltage rating (400 V)               |     |     |    |    |   |     |
| 6           | C = two diodes common cathode        |     |     |    |    |   |     |
| 7           | Lead (Pb)-free                       |     |     |    |    |   |     |

| LINKS TO RELATED DOCUMENTS |                                                                        |
|----------------------------|------------------------------------------------------------------------|
| Dimensions                 | <a href="http://www.vishay.com/doc?95021">www.vishay.com/doc?95021</a> |



## TO-244

**DIMENSIONS** in millimeters (inches)





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